

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Extended temperature range T_i = 175 °C
- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm
- Tin-plated 100% solderable side pads for optical solder inspection
- ElectroStatic Discharge (ESD) protection > 1.5 kV HBM
- Trench MOSFET technology
- AEC-Q101 qualified

3. Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

4. Quick reference data

| Table 1. Quick I | reference data | | | | | | |
|------------------------|----------------------------------|---|-----|-----|-----|-----|------|
| Symbol | Parameter | Conditions | | Min | Тур | Мах | Unit |
| V _{DS} | drain-source voltage | T _j = 25 °C | | - | - | 30 | V |
| V _{GS} | gate-source voltage | | | -12 | - | 12 | V |
| I _D | drain current | V_{GS} = 4.5 V; T_{amb} = 25 °C | [1] | - | - | 3.8 | А |
| Static characteristics | | | | | | | |
| R _{DSon} | drain-source on-state resistance | V _{GS} = 4.5 V; I _D = 3.8 A; T _j = 25 °C | | - | 55 | 72 | mΩ |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

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5. Pinning information

| Table 2. | Pinning in | formation | | |
|----------|------------|-------------|-----------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | D | drain | | D |
| 2 | D | drain | | |
| 3 | G | gate | | G ← → ☆ ↓ |
| 4 | S | source | | |
| 5 | D | drain | Transparent top view | |
| 6 | D | drain | DFN2020MD-6 (SOT1220) | ' S |
| 7 | D | drain | | 017aaa255 |
| 8 | S | source | | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | age | | | | |
|-------------|-------------|---|---------|--|--|--|
| | Name | Description | Version | | | |
| PMPB55XNEA | DFN2020MD-6 | DFN2020MD-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals | SOT1220 | | | |

7. Marking

| Table 4. Marking codes | |
|------------------------|--------------|
| Type number | Marking code |
| PMPB55XNEA | 3Q |

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|----------------------|---|---|-----|-----|------|------|
| V _{DS} | drain-source voltage | T _j = 25 °C | | - | 30 | V |
| V _{GS} | gate-source voltage | | | -12 | 12 | V |
| I _D | drain current | V _{GS} = 4.5 V; T _{amb} = 25 °C | [1] | - | 3.8 | А |
| | | V _{GS} = 4.5 V; T _{amb} = 100 °C | [1] | - | 2.4 | А |
| I _{DM} | peak drain current | T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$ | | - | 16 | А |
| E _{DS(AL)S} | non-repetitive drain- source avalanche energy | $T_{j(init)}$ = 25 °C; I _D = 0.3 A; DUT in avalanche (unclamped) | | - | 6.2 | mJ |
| P _{tot} | total power dissipation | T _{amb} = 25 °C | [2] | - | 550 | mW |
| | | | [1] | - | 1.95 | W |
| | | T _{sp} = 25 °C | | - | 10 | W |
| Tj | junction temperature | | | -55 | 175 | °C |
| T _{amb} | ambient temperature | | | -55 | 175 | °C |
| T _{stg} | storage temperature | | | -65 | 175 | °C |
| Source-drai | n diode | | | | | |
| I _S | source current | T _{amb} = 25 °C | [1] | - | 1.9 | А |
| ESD maxim | um rating | | | | | |
| V _{ESD} | electrostatic discharge voltage | НВМ | [3] | - | 1500 | V |

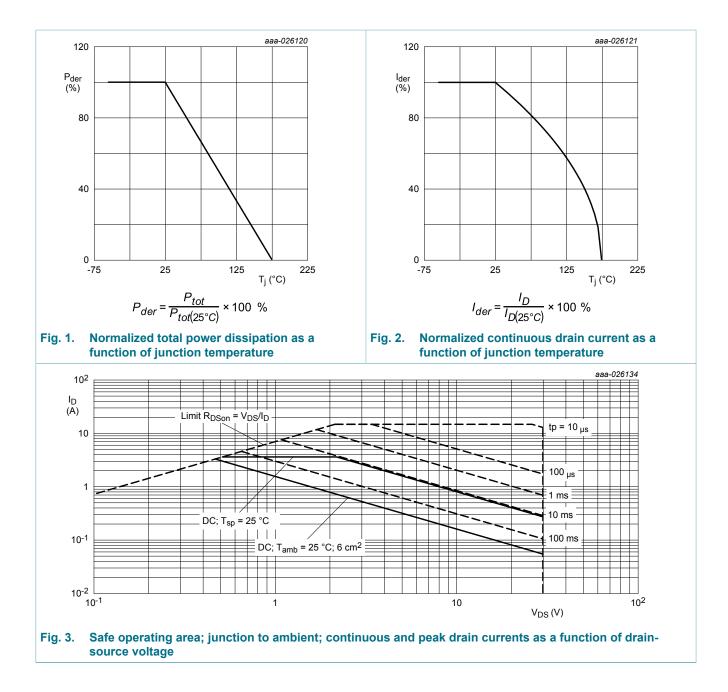
Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm². [1]

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper; tin-plated and standard footprint. Measures between all pins.

[2] [3]

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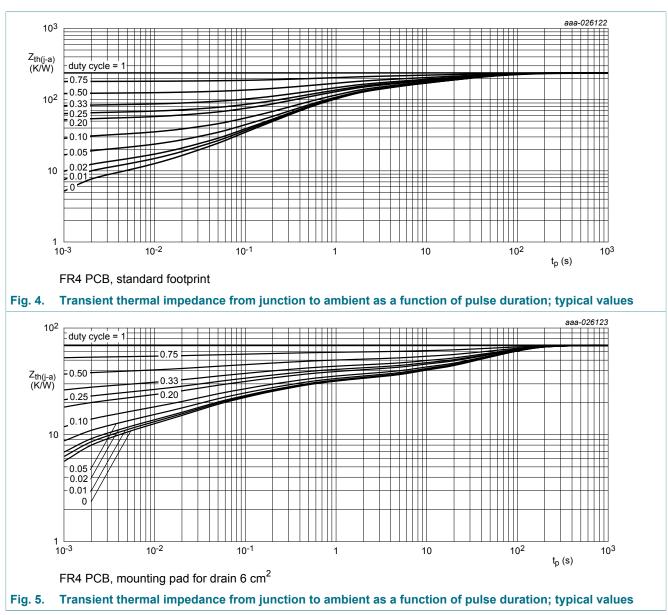


9. Thermal characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-----------------------|--|-------------|-----|-----|-----|-----|------|
| R _{th(j-a)} | thermal resistance | in free air | [1] | - | 236 | 272 | K/W |
| | from junction to ambient | | [2] | - | 67 | 77 | K/W |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | | - | 12 | 15 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

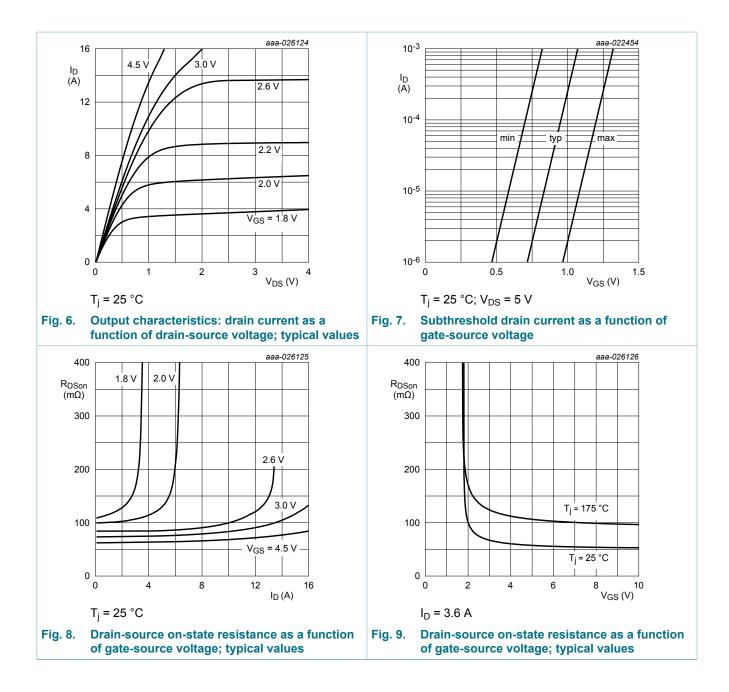
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10. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|-----------------------------------|--|------|------|------|------|
| Static chara | acteristics | | | | 1 | |
| V _{(BR)DSS} | drain-source breakdown voltage | I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C | 30 | - | - | V |
| V _{GSth} | gate-source threshold voltage | $I_D = 250 \ \mu A; V_{DS} = V_{GS}; T_j = 25 \ ^{\circ}C$ | 0.75 | 1 | 1.25 | V |
| I _{DSS} | drain leakage current | V _{DS} = 30 V; V _{GS} = 0 V; T _j = 25 °C | - | - | 1 | μA |
| I _{GSS} | gate leakage current | V _{GS} = 12 V; V _{DS} = 0 V; T _j = 25 °C | - | - | 10 | μA |
| | | V_{GS} = -12 V; V_{DS} = 0 V; T_j = 25 °C | - | - | -10 | μA |
| | | V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C | - | - | 2 | μA |
| | | V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C | - | - | -2 | μA |
| R _{DSon} | drain-source on-state | V _{GS} = 4.5 V; I _D = 3.8 A; T _j = 25 °C | - | 55 | 72 | mΩ |
| | resistance | V _{GS} = 4.5 V; I _D = 3.8 A; T _j = 175 °C | - | 102 | 133 | mΩ |
| | | V _{GS} = 2.5 V; I _D = 3.1 A; T _j = 25 °C | - | 77 | 110 | mΩ |
| 9 _{fs} | forward transconductance | V _{DS} = 10 V; I _D = 3.8 A; T _j = 25 °C | - | 20 | - | S |
| R _G | gate resistance | f = 1 MHz | - | 10.8 | - | Ω |
| Dynamic cł | naracteristics | | | | | |
| Q _{G(tot)} | total gate charge | V_{DS} = 15 V; I _D = 3.6 A; V _{GS} = 4.5 V; | - | 3 | 5 | nC |
| Q _{GS} | gate-source charge | T _j = 25 °C | - | 0.5 | - | nC |
| Q _{GD} | gate-drain charge | | - | 0.9 | - | nC |
| C _{iss} | input capacitance | V _{DS} = 15 V; f = 1 MHz; V _{GS} = 0 V; | - | 255 | - | pF |
| C _{oss} | output capacitance | T _j = 25 °C | - | 31 | - | pF |
| C _{rss} | reverse transfer capacitance | | - | 23 | - | pF |
| t _{d(on)} | turn-on delay time | V_{DS} = 15 V; I _D = 3.6 A; V _{GS} = 4.5 V; | - | 7 | - | ns |
| t _r | rise time | $R_{G(ext)} = 6 \Omega; T_j = 25 °C$ | - | 20 | - | ns |
| t _{d(off)} | turn-off delay time | 1 | - | 18 | - | ns |
| t _f | fall time | | - | 8 | - | ns |
| Source-dra | in diode | · · · | | | | |
| V _{SD} | source-drain voltage | I _S = 1.9 A; V _{GS} = 0 V; T _j = 25 °C | - | 0.8 | 1.2 | V |
| t _{rr} | reverse recovery time | $I_{\rm S}$ = 2.5 A; dI _S /dt = -100 A/µs; | - | 12.6 | - | ns |
| Qr | recovered charge | V _{GS} = 0 V; V _{DS} = 10 V; T _j = 25 °C | - | 4 | - | nC |

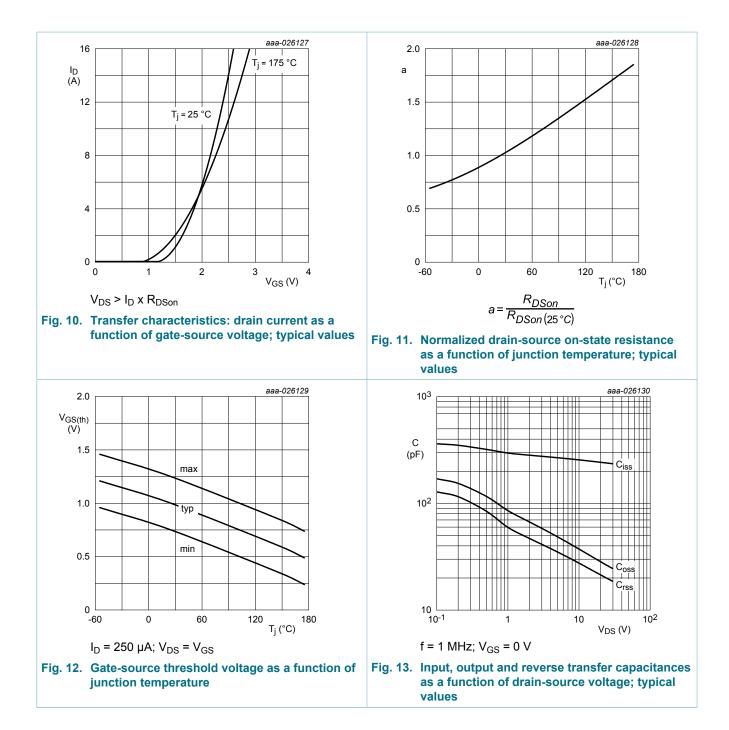
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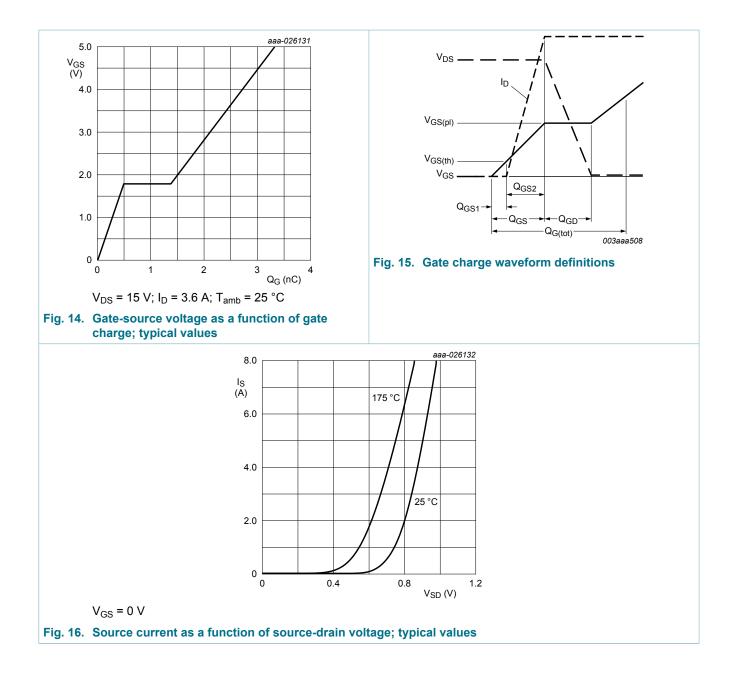
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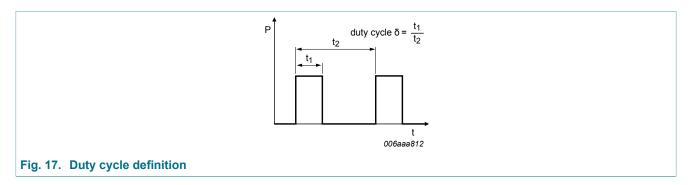
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11. Test information



Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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12. Package outline

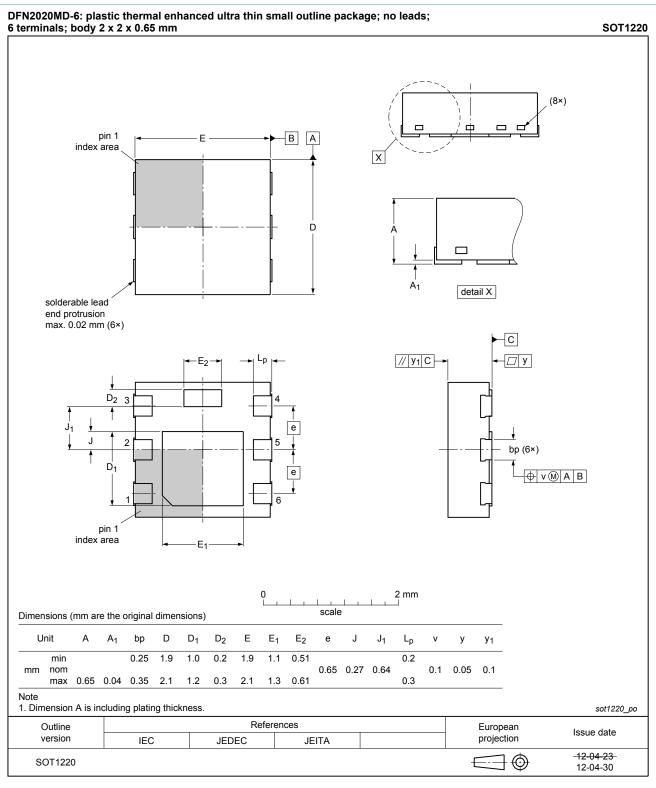
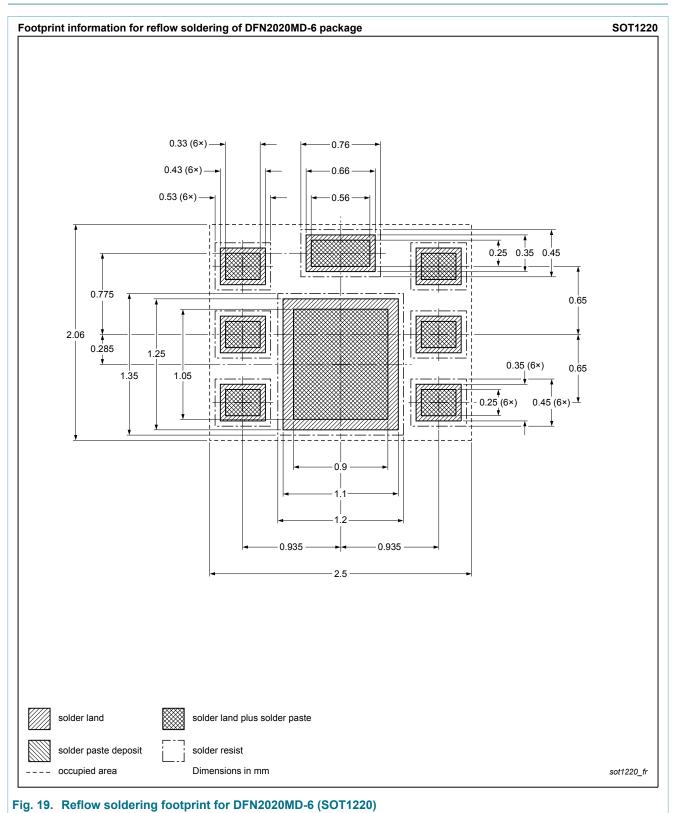


Fig. 18. Package outline DFN2020MD-6 (SOT1220)

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13. Soldering



PMPB55XNEA

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14. Revision history

| Table 8. Revision history | | | | | | | |
|---------------------------|------------------------|--------------------|---------------|----------------|--|--|--|
| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes | | | |
| PMPB55XNEA v.2 | 20170329 | Product data sheet | - | PMPB55XNEA v.1 | | | |
| Modifications> | Marking code corrected | | | | | | |
| PMPB55XNEA v.1 | 20170222 | Product data sheet | - | - | | | |

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15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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